

CMOS Digital Integrated Circuits Silicon Monolithic

## TC7WH14FU

### 1. Functional Description

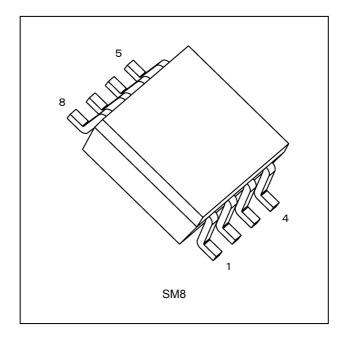
Triple Schmitt Inverter

### 2. Features

- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- High speed operation:  $t_{pd}$  = 5.5 ns (typ.) ( $V_{CC}$  = 5.0 V,  $C_{L}$  = 15 pF)
- Low power dissipation:  $I_{CC} = 2.0 \mu A \text{ (max) (} T_a = 25 \text{ °C)}$
- (4) High noise immunity:  $V_{NIH} = V_{NIL} = 28 \% V_{CC}$  (min)
- 5.5 V tolerant inputs
- (6)Balanced propagation delays: t<sub>PLH</sub> ≈ t<sub>PHL</sub>
- (7)Wide operating voltage range:  $V_{\rm CC}$  = 2.0 to 5.5 V
- Identical pin assignment and function with TC7W14

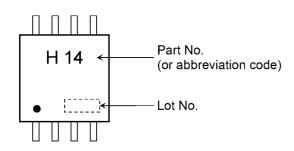
Note 1: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

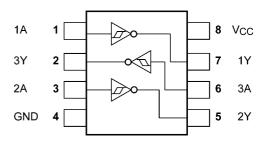
### 3. Packaging





## 4. Marking and Pin Assignment





Marking

Pin Assignment (Top view)

## 5. IEC Logic Symbol



#### 6. Truth Table

| А | Υ |
|---|---|
| L | Н |
| Н | L |

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 7.0                   | V    |
| Input voltage                   | $V_{IN}$         |          | -0.5 to 7.0                   |      |
| DC output voltage               | V <sub>OUT</sub> |          | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  | (Note 1) | ±20                           |      |
| DC output current               | I <sub>OUT</sub> |          | ±25                           |      |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           |      |
| Power dissipation               | $P_D$            |          | 300                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>



## 8. Operating Ranges (Note)

| Characteristics       | Symbol           | Note     | Test Condition | Rating               | Unit |
|-----------------------|------------------|----------|----------------|----------------------|------|
| Supply voltage        | V <sub>CC</sub>  |          | _              | 2.0 to 5.5           | V    |
| Input voltage         | V <sub>IN</sub>  |          | _              | 0 to 5.5             |      |
| Output voltage        | V <sub>OUT</sub> |          | _              | 0 to V <sub>CC</sub> |      |
| Operating temperature | T <sub>opr</sub> | (Note 1) | _              | -40 to 125           | °C   |
|                       |                  | (Note 2) | _              | -40 to 85            |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: For devices with the ordering part number ending in J(CT.

Note 2: For devices except those with the ordering part number ending in J(CT.

## 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics            | Symbol          | Test Condition                           |                          | V <sub>CC</sub> (V) | Min  | Тур. | Max  | Unit |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------|------|
| Positive threshold voltage | V <sub>P</sub>  | _  |                          | 3.0                 | _    | _    | 2.20 | V    |
|                            |                 |  |                          | 4.5                 | _    | _    | 3.15 |      |
|                            |                 |  |                          | 5.5                 | _    |      | 3.85 |      |
| Negative threshold voltage | V <sub>N</sub>  | _  |                          | 3.0                 | 0.90 | _    | _    | V    |
|                            |                 |  |                          | 4.5                 | 1.35 |      | _    |      |
|                            |                 |  |                          | 5.5                 | 1.65 |      | _    |      |
| Hysteresis voltage         | V <sub>H</sub>  | _  |                          | 3.0                 | 0.30 | _    | 1.20 | V    |
|                            |                 |  |                          | 4.5                 | 0.40 |      | 1.40 |      |
|                            |                 |  |                          | 5.5                 | 0.50 | _    | 1.60 |      |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | 2.0  | _    | V    |
|                            |                 |  |                          | 3.0                 | 2.9  | 3.0  | _    |      |
|                            |                 |  |                          | 4.5                 | 4.4  | 4.5  | _    |      |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.58 |      | _    |      |
|                            |                 |  | $I_{OH}$ = -8 mA         | 4.5                 | 3.94 |      |      |      |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.0  | 0.1  | V    |
|                            |                 |  |                          | 3.0                 | _    | 0.0  | 0.1  |      |
|                            |                 |  |                          | 4.5                 | _    | 0.0  | 0.1  |      |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | _    | 0.36 |      |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | _    | 0.36 |      |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           |                          | 0 to 5.5            | _    |      | ±0.1 | μА   |
| Quiescent supply current   | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 | _    | _    | 2.0  | μА   |



## 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics            | Symbol          | Test Con                                 | dition                   | V <sub>CC</sub> (V) | Min  | Max  | Unit       |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------------|
| Positive threshold voltage | V <sub>P</sub>  | _  |                          | 3.0                 | _    | 2.20 | V          |
|                            |                 |  |                          | 4.5                 | _    | 3.15 |            |
|                            |                 |  |                          | 5.5                 | _    | 3.85 | ]          |
| Negative threshold voltage | V <sub>N</sub>  | _  |                          | 3.0                 | 0.90 | _    | V          |
|                            |                 |  |                          | 4.5                 | 1.35 | _    |            |
|                            |                 |  |                          | 5.5                 | 1.65 | _    | ]          |
| Hysteresis voltage         | V <sub>H</sub>  | _  |                          | 3.0                 | 0.30 | 1.20 | V          |
|                            |                 |  |                          | 4.5                 | 0.40 | 1.40 |            |
|                            |                 |  |                          | 5.5                 | 0.50 | 1.60 | ]          |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | _    | V          |
|                            |                 |  |                          | 3.0                 | 2.9  | _    |            |
|                            |                 |  |                          | 4.5                 | 4.4  | _    | 1 I        |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.48 | _    | ]          |
|                            |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.80 | _    |            |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.1  | V          |
|                            |                 |  |                          | 3.0                 | _    | 0.1  | ]          |
|                            |                 |  |                          | 4.5                 | _    | 0.1  | ]          |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | 0.44 | 1 I        |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | 0.44 | 1 <b> </b> |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           | •                        | 0 to 5.5            | _    | ±1.0 | μА         |
| Quiescent supply current   | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 | _    | 20.0 | μА         |

## 9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C)

| Characteristics            | Symbol          | Test Cond                                | lition                   | V <sub>CC</sub> (V) | Min  | Max  | Unit |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------|
| Positive threshold voltage | $V_P$           | _  |                          | 3.0                 | _    | 2.20 | V    |
|                            |                 |  |                          | 4.5                 | _    | 3.15 |      |
|                            |                 |  |                          | 5.5                 | _    | 3.85 |      |
| Negative threshold voltage | V <sub>N</sub>  | _  |                          | 3.0                 | 0.90 | _    | V    |
|                            |                 |  |                          | 4.5                 | 1.35 | _    |      |
|                            |                 |  |                          | 5.5                 | 1.65 | _    | ]    |
| Hysteresis voltage         | V <sub>H</sub>  | _  |                          | 3.0                 | 0.30 | 1.20 | V    |
|                            |                 |  |                          | 4.5                 | 0.40 | 1.40 | ]    |
|                            |                 |  |                          | 5.5                 | 0.50 | 1.60 | ]    |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | _    | V    |
|                            |                 |  |                          | 3.0                 | 2.9  | _    |      |
|                            |                 |  |                          | 4.5                 | 4.4  | _    | ]    |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.40 | _    | ]    |
|                            |                 |  | $I_{OH} = -8 \text{ mA}$ | 4.5                 | 3.70 | _    |      |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.1  | V    |
|                            |                 |  |                          | 3.0                 | _    | 0.1  | ]    |
|                            |                 |  |                          | 4.5                 | _    | 0.1  |      |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | 0.55 | ]    |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | 0.55 |      |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           |                          | 0 to 5.5            | _    | ±2.0 | μА   |
| Quiescent supply current   | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 | _    | 40.0 | μА   |

Note: For devices with the ordering part number ending in J(CT.



## 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol                             | Note     | Test<br>Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|-------------------------------|------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|------|
| Propagation delay time        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | _                 | $3.3 \pm 0.3$       | 15                  | _   | 8.3  | 12.8 | ns   |
|                               |                                    |          |                   |                     | 50                  | _   | 10.8 | 16.3 |      |
|                               |                                    |          |                   | $5.0 \pm 0.5$       | 15                  | _   | 5.5  | 8.6  |      |
|                               |                                    |          |                   |                     | 50                  | _   | 7.0  | 10.6 |      |
| Input capacitance             | C <sub>IN</sub>                    |          | _                 |                     |                     | _   | 4    | 10   | pF   |
| Power dissipation capacitance | $C_{PD}$                           | (Note 1) |                   |                     |                     |     | 12   | 1    | pF   |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/3 \text{ (per 1 gate)}$ 

## 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Test Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|----------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | _              | $3.3 \pm 0.3$       | 15                  | 1.0 | 15.0 | ns   |
|                        |                                    |                |                     | 50                  | 1.0 | 18.5 |      |
|                        |                                    |                | 5.0 ± 0.5           | 15                  | 1.0 | 10.0 |      |
|                        |                                    |                |                     | 50                  | 1.0 | 12.0 |      |
| Input capacitance      | C <sub>IN</sub>                    |                |                     |                     | _   | 10   | pF   |

# 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

| Characteristics        | Symbol                             | Test Condition | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|----------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | _              | $3.3 \pm 0.3$       | 15                  | 1.0 | 17.0 | ns   |
|                        |                                    |                |                     | 50                  | 1.0 | 20.5 |      |
|                        |                                    |                | 5.0 ± 0.5           | 15                  | 1.0 | 11.5 |      |
|                        |                                    |                |                     | 50                  | 1.0 | 13.5 |      |
| Input capacitance      | C <sub>IN</sub>                    | _              |                     |                     | _   | 10   | pF   |

Note: For devices with the ordering part number ending in J(CT.

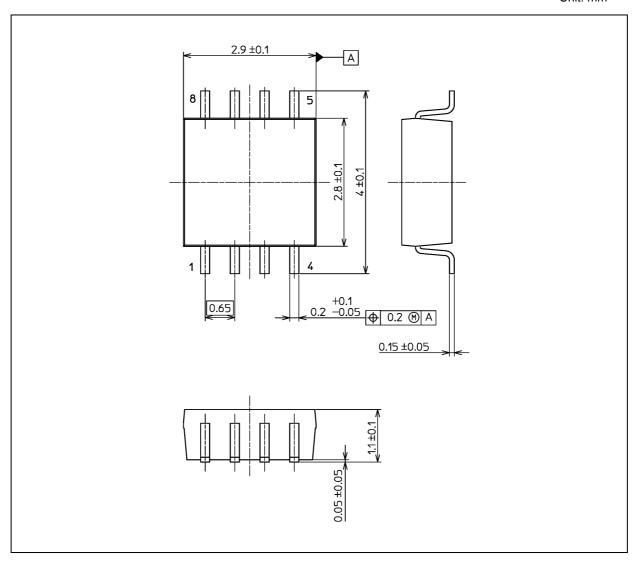
## 9.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

| Characteristics                              | Symbol           | Test Condition         | V <sub>CC</sub> (V) | Тур. | Limit | Unit |
|--|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.3  | 0.8   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.3 | -0.8  | V    |
| Minimum high-level dynamic input voltage     | $V_{IHD}$        | C <sub>L</sub> = 50 pF | 5.0                 | _    | 3.5   | V    |
| Maximum low-level dynamic input voltage      | $V_{ILD}$        | C <sub>L</sub> = 50 pF | 5.0                 |      | 1.5   | V    |



## **Package Dimensions**

Unit: mm



Weight: 21 mg (typ.)

|                | Package Name(s) |  |
|----------------|-----------------|--|
| JEDEC: SOT-505 |                 |  |
| Nickname: SM8  |                 |  |



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